AEC Qualified RoHS

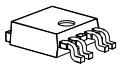
Smart Highside Power Switch

Reversave™
- Reverse battery protection by self turn on of power MOSFET

Features
- Short circuit protection with latch
- Current limitation
- Overload protection
- Thermal shutdown with restart
- Overvoltage protection (including load dump)
- Loss of ground protection
- Loss of V_{bb} protection (with external diode for charged inductive loads)
- Very low standby current
- Fast demagnetisation of inductive loads
- **E**lectro**s**tatic **d**ischarge (**ESD**) protection
- Optimized static **e**lectro**m**agnetic **c**ompatibility (**EMC**)
- Green Product (RoHS compliant)
- AEC qualified

Product Summary			
Operating voltage	$V_{bb(on)}$	5.5 ... 38	V
On-state resistance	R_{ON}	10	mΩ
Nominal current	$I_{L(nom)}$	8	A
Load current (ISO)	$I_{L(ISO)}$	33	A
Current limitation	$I_{L12(SC)}$	75	A

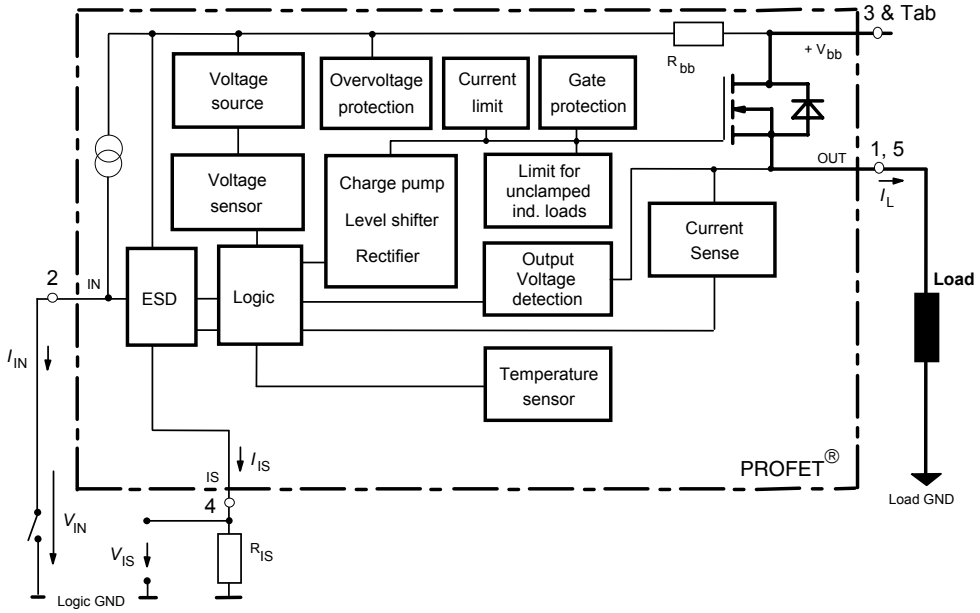
Package
PG-TO252-5-11
(DPAK 5 pin; less than half the size as TO 220 SMD)



Diagnostic Function
- Proportional load current sense (with defined fault signal in case of overload operation, overtemperature shutdown and/or short circuit shutdown)

Application
- Power switch with current sense diagnostic feedback for 12V and 24 V DC grounded loads
- All types of resistive, inductive and capacitive loads
- Replaces electromechanical relays, fuses and discrete circuits

General Description
N channel vertical power FET with charge pump, current controlled input and diagnostic feedback with load current sense, integrated in Smart SIPMOS® chip on chip technology. Providing embedded protective functions.



Pin	Symbol		Function
1	OUT	O	**Output;** output to the load; pin 1 and 5 must be externally shorted* .
2	IN	I	**Input;** activates the power switch if shorted to ground.
Tab/(3)	Vbb	+	**Supply Voltage;** positive power supply voltage; tab and pin3 are internally shorted.
4	IS	S	**Sense Output;** Diagnostic feedback; provides at normal operation a sense current proportional to the load current; in case of overload, overtemperature and/or short circuit a defined current is provided (see Truth Table on page 8)
5	OUT	O	**Output;** output to the load; pin 1 and 5 must be externally shorted* .

*) Not shorting all outputs will considerably increase the on-state resistance, reduce the peak current capability and decrease the current sense accuracy

Maximum Ratings at T_j = 25 °C unless otherwise specified

Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 4)	V_{bb}	38	V
Supply voltage for full short circuit protection [1]	V_{bb}	30	V
Load dump protection $V_{LoadDump} = U_A + V_s$, U_A = 13.5 V R_I= 2 Ω, R_L= 1.5 Ω, t_d= 400 ms, IN= low or high	$V_{Load\ dump}$[2]	45	V
Load current (Short-circuit current, see page 5)	I_L	self-limited	A
Operating temperature range Storage temperature range	T_j T_{stg}	-40 ...+150 -55 ...+150	°C
Power dissipation (DC)	P_{tot}	59	W
Inductive load switch-off energy dissipation [3] single pulse I_L = 20 A, V_{bb}= 12V T_j=150 °C:	E_{AS}	0.3	J
Electrostatic discharge capability (ESD) (Human Body Model) acc. ESD assn. std. S5.1-1993; R=1.5kΩ; C=100pF	V_{ESD}	3.0	kV
Current through input pin (DC) Current through current sense pin (DC) see internal circuit diagrams page 9	I_{IN} I_{IS}	+15, -120 +15, -120	mA
Input voltage slew rate V_{bb} ≤ 16V : V_{bb} > 16V [4]:	dV_{bIN}/dt	self-limited 20	V/µs

1) Short circuit is defined as a combination of remaining resistances and inductances. See schematic on page11.

2) $V_{Load\ dump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839.

3) See also diagram on page 11.

4) See also on page 8. Slew rate limitation can be achieved by means of using a series resistor R_{IN} in the input path. This resistor is also required for reverse operation. See also page 10.

Thermal Characteristics

Parameter and Conditions	Symbol	Values			Unit
		min	typ	max	
Thermal resistance chip - case:	R_{thJC}	--	--	1.1	K/W
junction - ambient (free air):	R_{thJA}	--	80	--	
SMD version, device on PCB [6]		--	45	55	

Electrical Characteristics

Parameter and Conditions at T_j= 25, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Load Switching Capabilities and Characteristics					
On-state resistance (pin 3 to pin 1,5)					
V_{IN}= 0, V_{bb}= 5.5V, I_L = 7.5 A T_j=25 °C:	R_{ON}	--	10	14	mΩ
T_j=150 °C:		--	18	24	
V_{IN}= 0, V_{bb}= 12V, I_L = 7.5 A T_j=25 °C:		--	8	10	
T_j=150 °C:		--	14	18	
Output voltage drop limitation at small load currents (Tab to pin 1,5) [5] T_j=-40...150 °C:	$V_{ON(NL)}$	--	30	65	mV
Nominal load current (Tab to pin 1,5)					
ISO Proposal: $V_{ON} \leq$ 0.5 V, T_C = 85°C, $T_j \leq$ 150°C	$I_{L(ISO)}$	33	41	--	A
SMD [6], $V_{ON} \leq$ 0.5 V, T_A = 85°C, $T_j \leq$ 150°C	$I_{L(nom)}$	8	10	--	
Turn-on time to 90% V_{OUT}:	t_{on}	--	250	500	µs
Turn-off time to 10% V_{OUT}:	t_{off}	--	250	500	
R_L = 2.2 Ω, T_j=-40...150 °C					
Slew rate on 25 to 50% V_{OUT}, R_L = 2.2 Ω, T_j=-40...150 °C	dV/dt_{on}	--	0.3	0.5	V/µs
Slew rate off 50 to 25% V_{OUT}, R_L = 2.2 Ω, T_j=-40...150 °C	$-dV/dt_{off}$	--	0.3	0.6	V/µs

5) See figure 7a on page 15.

6) Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70µm thick) copper area for V_{bb} connection. PCB is vertical without blown air.

Parameter and Conditions at T_j= 25, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Operating Parameters					
Operating voltage (V_{IN}=0) T_j=-40...150 °C:	$V_{bb(on)}$	5.5	--	38	V
Undervoltage shutdown [7] [8]	$V_{bIN(u)}$	--	2.5	3.5	V
Undervoltage restart of charge pump	$V_{bb(ucp)}$	--	4	5.5	V
Overvoltage protection [9]	$V_{Z,IN}$				V
I_{bb}=15 mA T_j=-40...+150°C:		63	67	--	
Standby current T_j=-40...+120°C:	$I_{bb(off)}$	--	3	6	µA
I_{IN}=0 T_j=150°C:		--	6	14	
Reverse Battery					
Reverse battery voltage [10]	$-V_{bb}$	--	--	16	V
On-state resistance (pin 1,5 to pin 3)					
V_{bb}= - 8V, V_{IN}= 0, I_L = -7.5 A, R_{IS} = 1 kΩ, [8]					
T_j=25 °C:	$R_{ON(rev)}$	--	9.5	13	mΩ
T_j=150 °C:		--	16	22	
V_{bb}= -12V, V_{IN}= 0, I_L = -7.5 A, R_{IS} = 1 kΩ, T_j=25 °C:		--	9	12	
T_j=150 °C:		--	15	20	
Integrated resistor in V_{bb} line	R_{bb}	--	100	150	Ω
Inverse Operation [11]					
Output voltage drop (pin 1,5 to pin 3) [8]					
I_L = -7.5 A, R_{IS} = 1 kΩ, T_j=25 °C:	$-V_{ON(inv)}$	--	700	--	mV
I_L = -7.5 A, R_{IS} = 1 kΩ, T_j=150 °C:		--	300	--	
Turn-on delay after inverse operation; I_L > 0A [8] V_{IN}(inv) = V_{IN}(fwd) = 0 V	$t_{d(inv)}$	--	1	--	ms

7) V_{bIN}=V_{bb}-V_{IN} see schematic on page 8 and page 14.

8) Not subject to production test, specified by design.

9) See also $V_{Z(IN)}$ in schematic page 9.

10) For operation at voltages higher then |16V| please see required schematic on page 10.

11) Permanent Inverse operation results eventually in a current flow via the intrinsic diode of the power DMOS. In this case the device switches on with a time delay $t_{d(inv)}$ after the transition from inverse to forward mode.

Parameter and Conditions at T_j= 25, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Protection Functions [12]					
Short circuit current limit (Tab to pin 1,5) [13]					
Short circuit current limit at V_{ON} = 6V [14] T_j =-40°C: T_j =25°C: T_j =+150°C:	$I_{L6(SC)}$	-- -- 70	110 105 90	140 -- --	A
Short circuit current limit at V_{ON} = 12V, t_m=170µs $T_{j(start)}$ =-40°C: $T_{j(start)}$ =25°C: $T_{j(start)}$ =+150°C:	$I_{L12(SC)}$	-- -- 45	80 75 60	110 -- --	A
Short circuit current limit at V_{ON} = 18V [14] $T_{j(start)}$ =-40°C: $T_{j(start)}$ =25°C: $T_{j(start)}$ =+150°C:	$I_{L18(SC)}$	-- -- 33	60 55 50	80 -- --	A
Short circuit current limit at V_{ON} = 24V, t_m=170µs $T_{j(start)}$ =-40°C: $T_{j(start)}$ =25°C: $T_{j(start)}$ =+150°C:	$I_{L24(SC)}$	-- -- 20	40 40 35	60 -- --	A
Short circuit current limit at V_{ON} = 30V [14] $T_{j(start)}$ =-40°C: $T_{j(start)}$ =25°C: $T_{j(start)}$ =+150°C:	$I_{L30(SC)}$	-- -- 15	25 25 25	40 -- --	A
Short circuit shutdown detection voltage (pin 3 to pins 1,5)	$V_{ON(SC)}$	2.5	3.5	4.5	V
Short circuit shutdown delay after input current positive slope, V_{ON} > $V_{ON(SC)}$, T_j =-40...+150°C min. value valid only if input "off-signal" time exceeds 30 µs	$t_{d(SC1)}$	350	650	1200	µs
Short circuit shutdown delay during on condition[14] V_{ON} > $V_{ON(SC)}$	$t_{d(SC2)}$	--	2	--	µs
Output clamp (inductive load switch off) [15] at V_{OUT} = V_{bb} - $V_{ON(CL)}$ (e.g. overvoltage) I_L= 40 mA	$V_{ON(CL)}$	39	42	--	V
Thermal overload trip temperature	T_{jt}	150	175	--	°C
Thermal hysteresis	ΔT_{jt}	--	10	--	K

[12] Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

[13] Short circuit current limit for max. duration of $t_{d(SC1)}$, prior to shutdown, see also figures 3.x on page 13.

[14] Not subject to production test, specified by design.

[15] See also figure 2b on page 12.

Parameter and Conditions at T_j= 25, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Diagnostic Characteristics					
Current sense ratio, static on-condition $k_{ILIS} = I_L : I_{IS}$, $I_{IS} < I_{IS,lim}$ [16], $V_{IS} < V_{OUT}$ - 5 V, $V_{bIN} > 4.5$ V	k_{ILIS}	--	10 000	--	
IL = 30A, Tj = -40°C:		8300	10000	11000	
Tj = +25°C:		8300	9700	10600	
Tj = +150°C:		8300	9300	10000	
IL = 7.5A, Tj = -40°C:		7500	10000	11400	
Tj = +25°C:		8000	9700	10800	
Tj = +150°C:		8200	9300	10200	
IL = 2.5A, Tj = -40°C:		7100	10000	13400	
Tj = +25°C:		7700	9700	12500	
Tj = +150°C:		8000	9300	12000	
IL = 0.5A, Tj = -40°C:		5000	12000	21000	
Tj = +25°C:		5500	12000	19000	
Tj = +150°C:		6000	12000	18000	
I_{IN} = 0 (e.g. during deenergizing of inductive loads):		--	0	--	
Sense current under fault conditions [17] V_{ON}>1V, typ T_j = -40...+150°C:	$I_{IS,fault}$	4.0	5.2	7.5	mA
Sense saturation current V_{ON}<1V, typ T_j = -40...+150°C:	$I_{IS,lim}$	4.0	6.0	7.5	mA
Fault-Sense signal delay after input current positive slope, V_{ON} >1V, T_j = -40...+150°C	$t_{delay(fault)}$	350	650	1200	µs
Current sense leakage current, I_{IN} = 0	$I_{IS(LL)}$	--	0.1	0.5	µA
Current sense offset current, V_{IN} = 0, $I_L \leq 0$	$I_{IS(LH)}$	--	0.1	1	µA
Minimum load current for sense functionality, V_{IN} = 0, T_j = -40...+150°C	$I_{L(MIN)}$	50	--	--	mA
Current sense settling time to $I_{IS\ static}$ after input current positive slope, [18] I_L = 0 ⎍ 20 A, T_j= -40...+150°C	$t_{son(IS)}$	--	250	500	µs
Current sense settling time during on condition, [18] I_L = 10 ⎍ 20 A, T_j= -40...+150°C	$t_{slc(IS)}$	--	50	100	µs
Overvoltage protection I_{bb} = 15 mA T_j = -40...+150°C:	$V_{Z,IS}$	63	67	--	V

16) See also figures 4.x and 6.x on page 13 and 14.

17) Fault conditions are overload during on (i.e. V_{ON}>1V typ.), overtemperature and short circuit; see also truth table on page 8.

18) Not subject to production test, specified by design.

Parameter and Conditions at T_j= 25, V_{bb} = 12 V unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Input					
Required current capability of input switch T_j =-40..+150°C:	$I_{IN(on)}$	--	1.4	2.2	mA
Input current for turn-off T_j =-40..+150°C:	$I_{IN(off)}$	--	--	30	µA

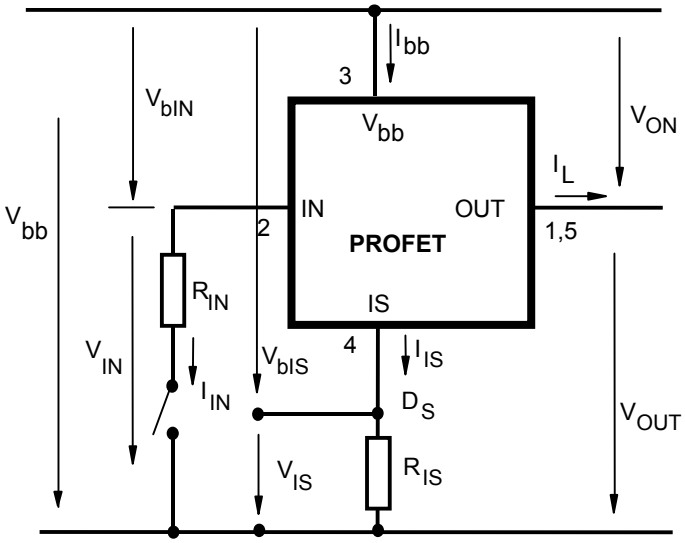
Truth Table

	Input Current level	Output level	Current Sense IIS
Normal operation	**L** **H**	**L** **H**	**≈0 ($I_{IS(LL)}$)** **nominal**
Overload [19]	**L** **H**	**L** **H**	**≈0 ($I_{IS(LL)}$)** **$I_{IS,fault}$**
Short circuit to GND [20]	**L** **H**	**L** **L**	**≈0 ($I_{IS(LL)}$)** **$I_{IS,fault}$**
Overtemperature	**L** **H**	**L** **L**	**≈0 ($I_{IS(LL)}$)** **$I_{IS,fault}$**
Short circuit to Vbb	**L** **H**	**H** **H**	**≈0 ($I_{IS(LL)}$)** **<nominal** [21]
Open load	**L** **H**	**Z** **H**	**≈0 ($I_{IS(LL)}$)** **≈0 ($I_{IS(LH)}$)**

L = "Low" Level
H = "High" Level

Z = high impedance, potential depends on external circuit

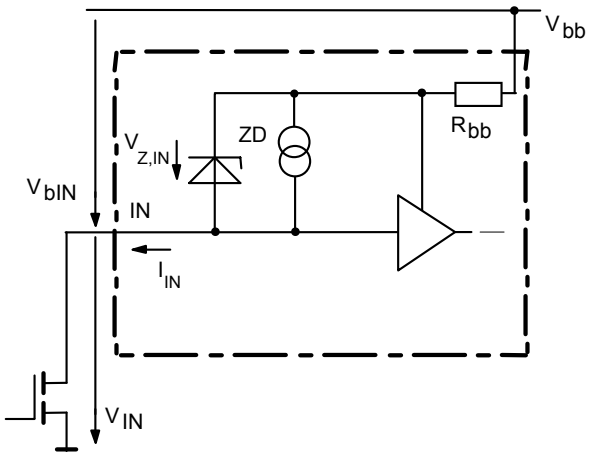
Terms



Two or more devices can easily be connected in parallel to increase load current capability.

[19] Overload is detected at the following condition: 1V (typ.) < V_{ON} < 3.5V (typ.) . See also page 11.
[20] Short Circuit is detected at the following condition: V_{ON} > 3.5V (typ.) . See also page 11.
[21] Low ohmic short to V_{bb} may reduce the output current I_L and therefore also the sense current I_{IS}.

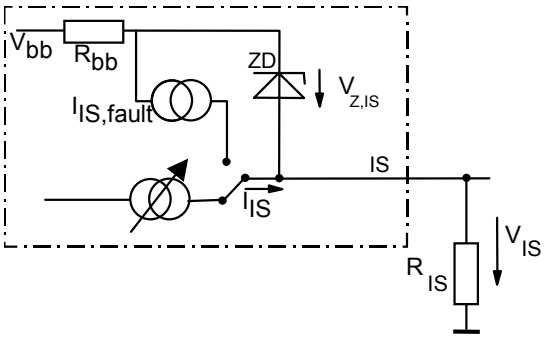
Input circuit (ESD protection)



ESD-Zener diode: 67 V typ., max 15 mA;

Current sense output

Normal operation

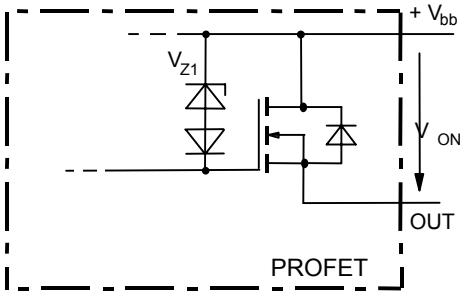


$V_{Z,IS}$ = 67 V (typ.), R_{IS} = 1 kΩ nominal (or 1 kΩ /n, if n devices are connected in parallel). $I_S = I_L/k_{ilis}$ can be only driven by the internal circuit as long as V_{out} - V_{IS} > 5V. Therefore R_{IS} should be less than

$$\frac{V_{bb} - 5V}{7.5mA}.$$

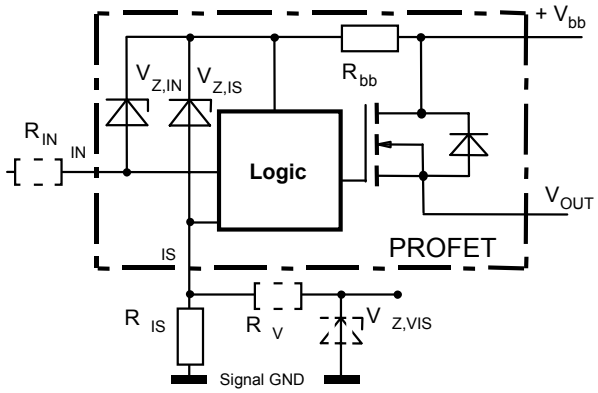
Note: *For large values of R_{IS} the voltage V_{IS} can reach almost V_{bb}. See also overvoltage protection.*
If you don't use the current sense output in your application, you can leave it open.

Inductive and overvoltage output clamp



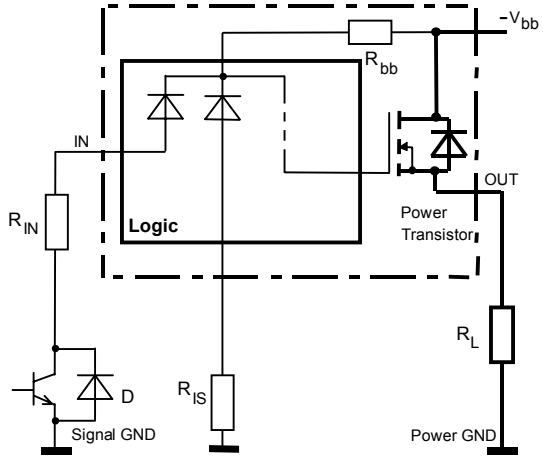
V_{ON} is clamped to $V_{ON(Cl)}$ = 42 V typ

Overvoltage protection of logic part



R_{bb} = 100 Ω typ., $V_{Z,IN}$ = $V_{Z,IS}$ = 67 V typ., R_{IS} = 1 kΩ nominal. Note that when overvoltage exceeds 67 V typ. a voltage above 5V can occur between IS and GND, if R_V, $V_{Z,VIS}$ are not used.

Reversave™ (Reverse battery protection)

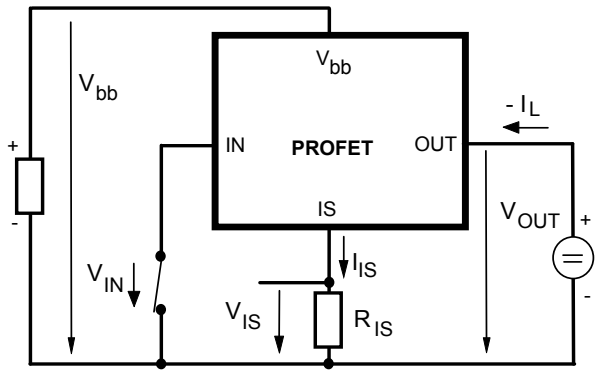


R_{IS} typ. 1 kΩ. Add R_{IN} for reverse battery protection in applications with V_{bb} above 16V;

recommended value: $\frac{1}{R_{IN}} + \frac{1}{R_{IS}} = \frac{0.08A}{|V_{bb}| - 12V}$

To minimise power dissipation at reverse battery operation, the overall current into the IN and IS pin should be about 80mA. The current can be provided by using a small signal diode D in parallel to the input switch, by using a MOSFET input switch or by proper adjusting the current through R_{IS}.
Since the current via R_{bb} generates additional heat in the device, this has to be taken into account in the overall thermal consideration.

Inverse load current operation

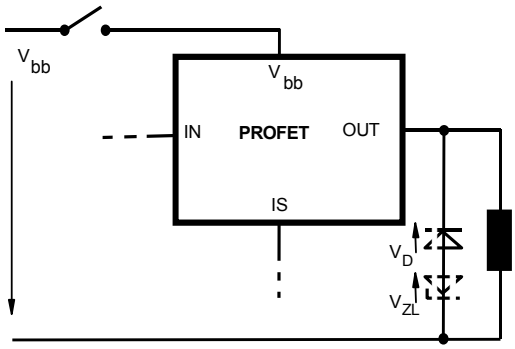


The device can be operated in inverse load current mode (V_{OUT} > V_{bb} > 0V). The current sense feature is not available during this kind of operation (I_{IS} = 0). In case of inverse operation the intrinsic drain source diode is eventually conducting resulting in considerably increased power dissipation.
The transition from inverse to forward mode can result in a delayed switch on.
Note: *Temperature protection during inverse load current operation is not possible!*

V_{bb} disconnect with energised inductive load

Provide a current path with load current capability by using a diode, a Z-diode, or a varistor. (V_{ZL}+V_D<39 V if R_{IN} = 0). For higher clamp voltages currents at IN and IS have to be limited to 120 mA.

Version a:

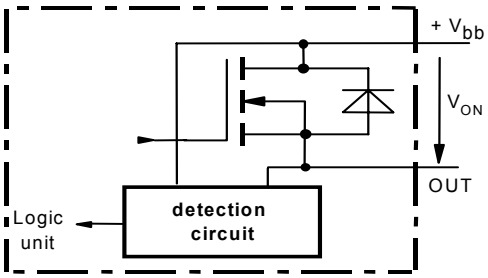


Short circuit detection

Fault Condition: $V_{ON} > V_{ON(SC)}$ (3.5 V typ.) and t> $t_{d(SC)}$ (typ.650 µs).

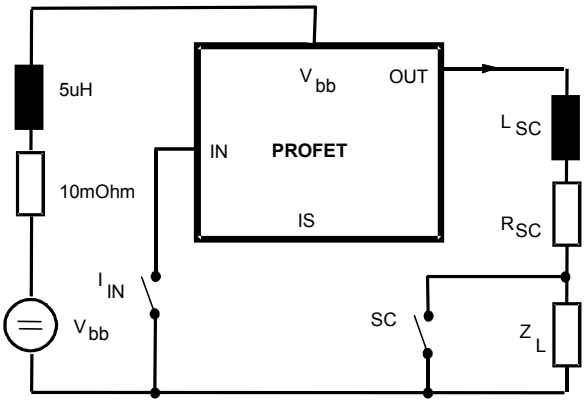
Overload detection

Fault Condition: $V_{ON} > 1$ V typ.

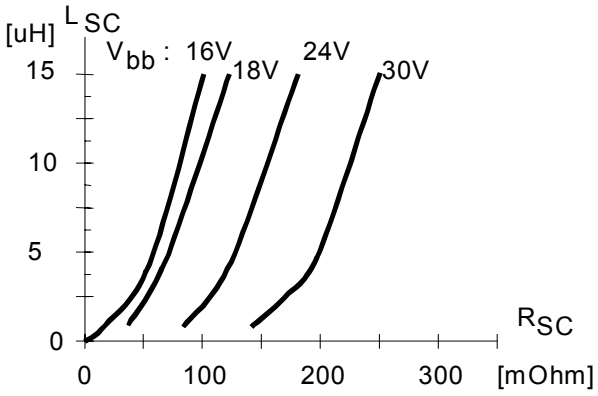


Short circuit

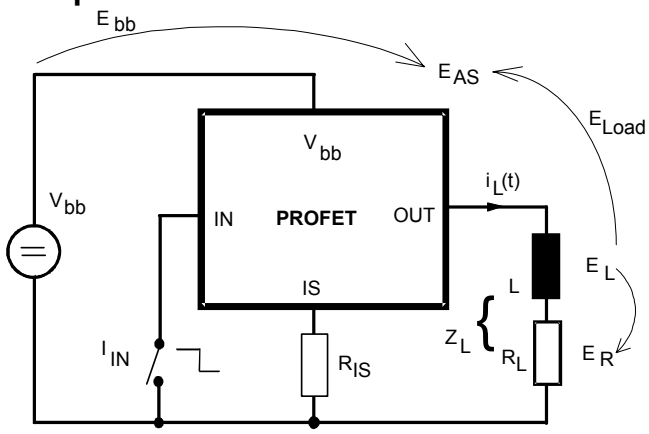
Short circuit is a combination of primary and secondary impedance's and a resistance's.



Allowable combinations of minimum, secondary resistance for full protection at given secondary inductance and supply voltage for single short circuit event:



Inductive load switch-off energy dissipation



Energy stored in load inductance:

$$E_L = {}^1/_2 \cdot L \cdot I_L^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is

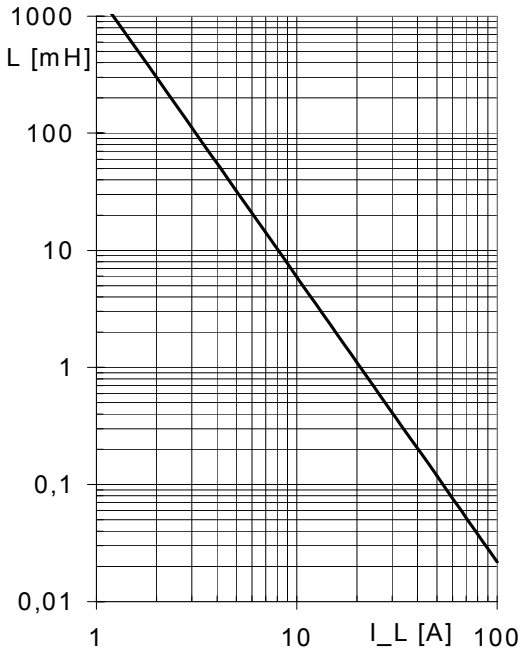
$$E_{AS} = E_{bb} + E_L - E_R = \int V_{ON(CL)} \cdot i_L(t)\, dt,$$

with an approximate solution for $R_L > 0\,\Omega$:

$$E_{AS} = \frac{I_L \cdot L}{2 \cdot R_L} \left(V_{bb} + |V_{OUT(CL)}| \right) \ ln \left(1 + \frac{I_L \cdot R_L}{|V_{OUT(CL)}|}\right)$$

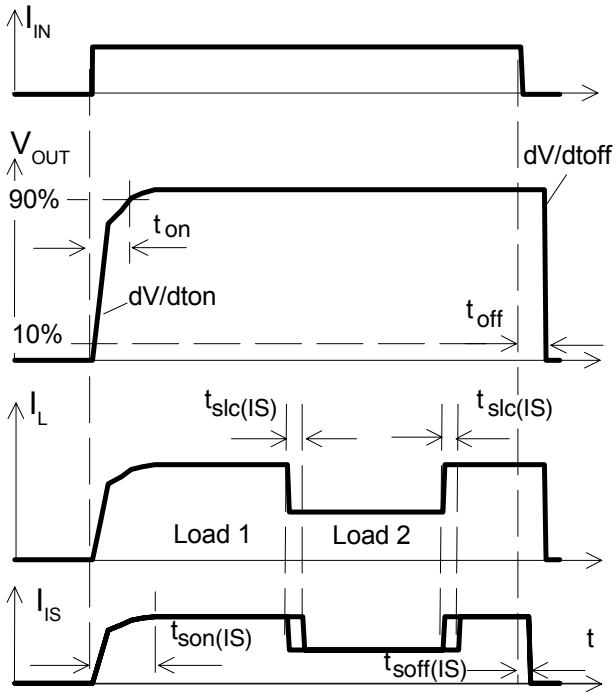
Maximum allowable load inductance for a single switch off

$L = f(I_L)$; $T_{j,start} = 150°C$, $V_{bb} = 12$ V, $R_L = 0\,\Omega$



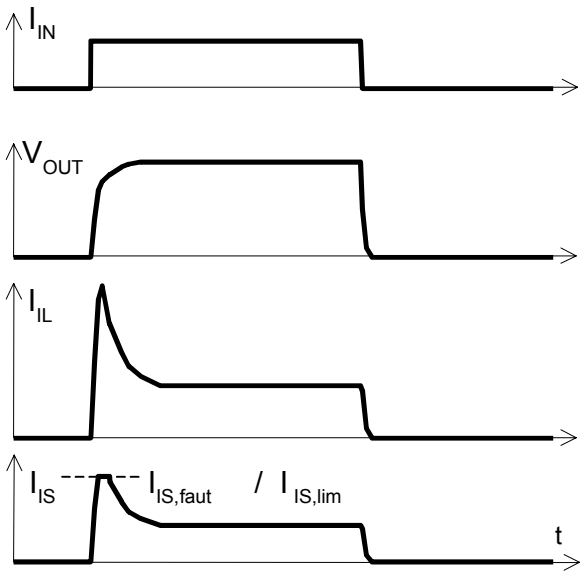
Timing diagrams

Figure 1a: Switching a resistive load, change of load current in on-condition:



The sense signal is not valid during a settling time after turn-on/off and after change of load current.

Figure 2a: Switching motors and lamps:



As long as $V_{bIS} < V_{Z,IS}$ the sense current will never exceed $I_{IS,fault}$ and/or $I_{IS,lim}$.

Figure 2b: Switching an inductive load:

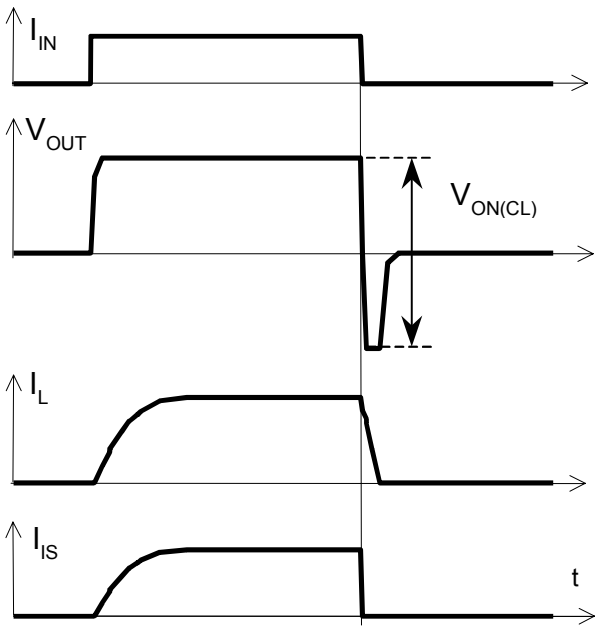
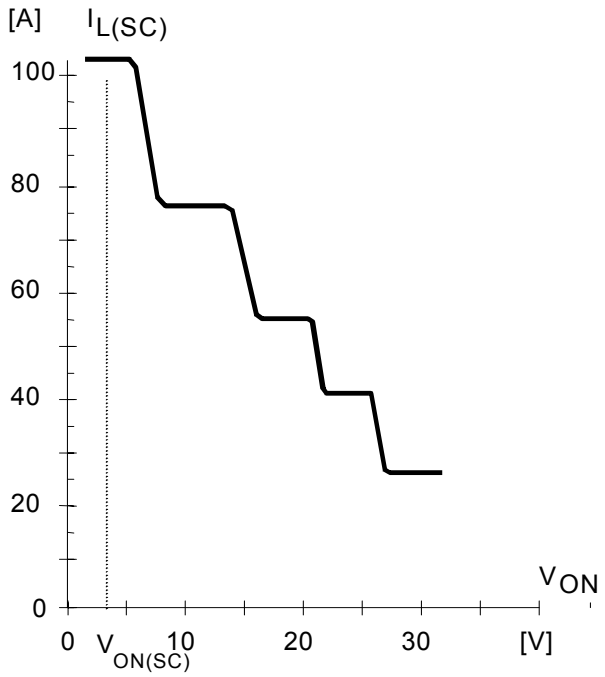
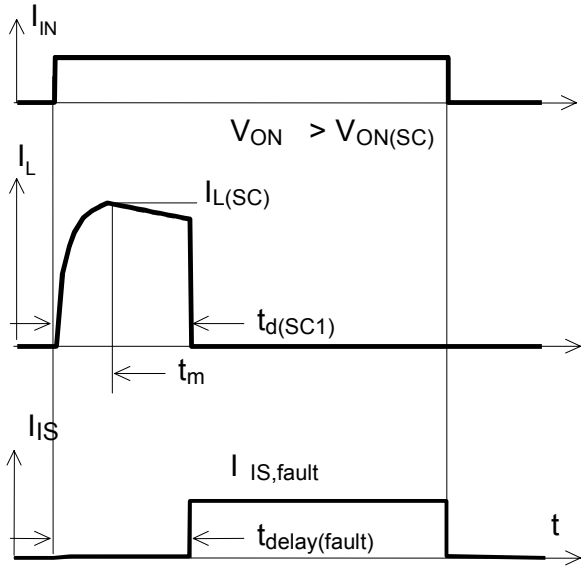


Figure 3a: Typ. current limitation characteristic



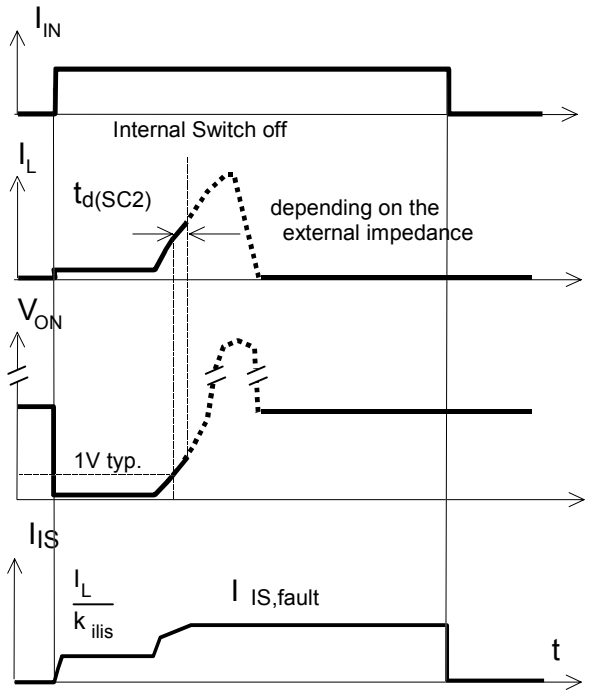
In case of $V_{ON} > V_{ON(SC)}$ (typ. 4 V) the device will be switched off by internal short circuit detection.

Figure 3b: Short circuit type one:
shut down by short circuit detection, reset by $I_{IN} = 0$.



Shut down remains latched until next reset via input.

Figure 3c: Short circuit type two:
shut down by short circuit detection, reset by $I_{IN} = 0$.



Shut down remains latched until next reset via input.

Figure 4a: Overtemperature
Reset if $T_j < T_{jt}$

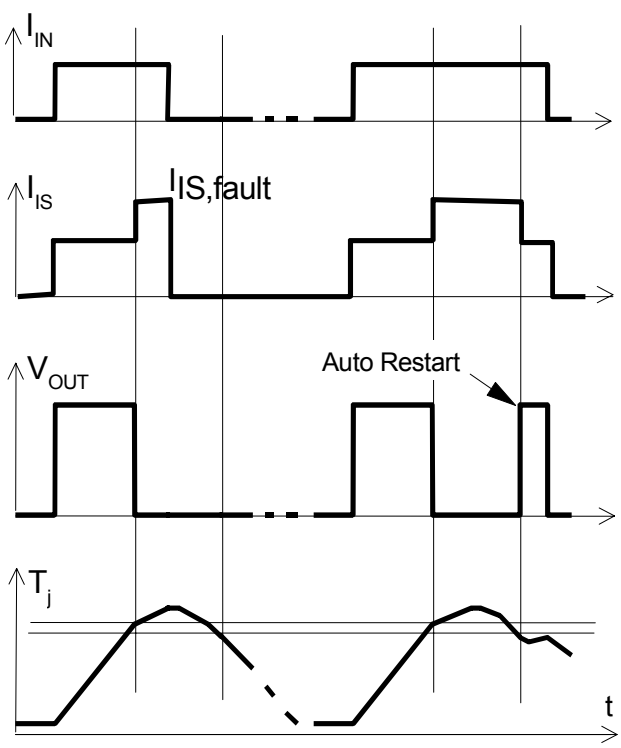


Figure 4b: Overload
$T_j < T_{jt}$

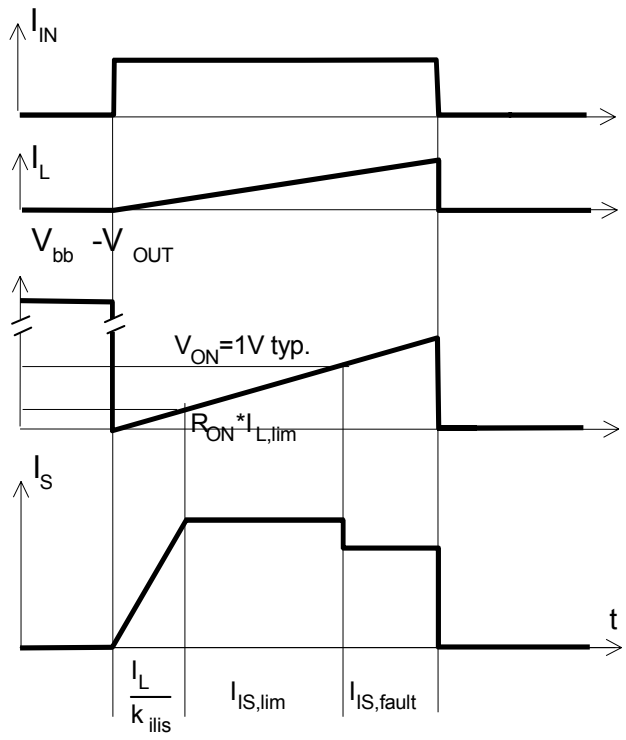


Figure 5a: Undervoltage restart of charge pump, overvoltage clamp

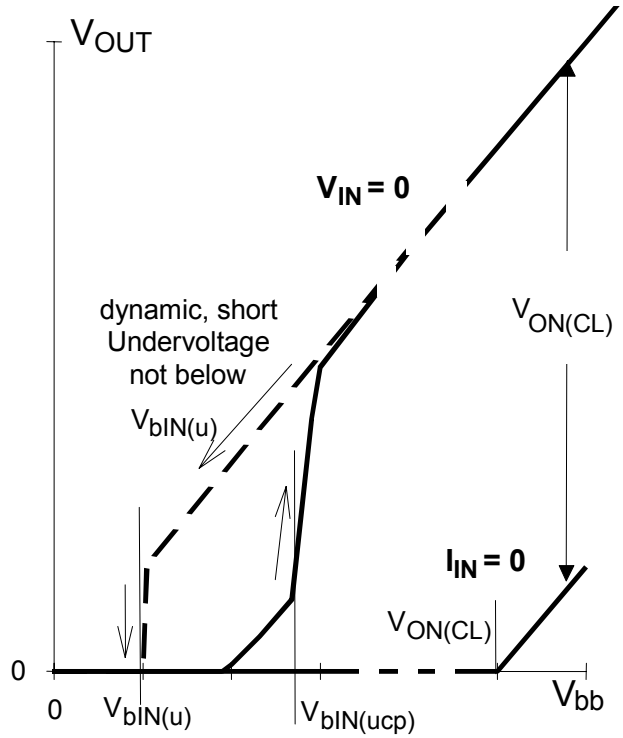


Figure 6a: Current sense versus load current:

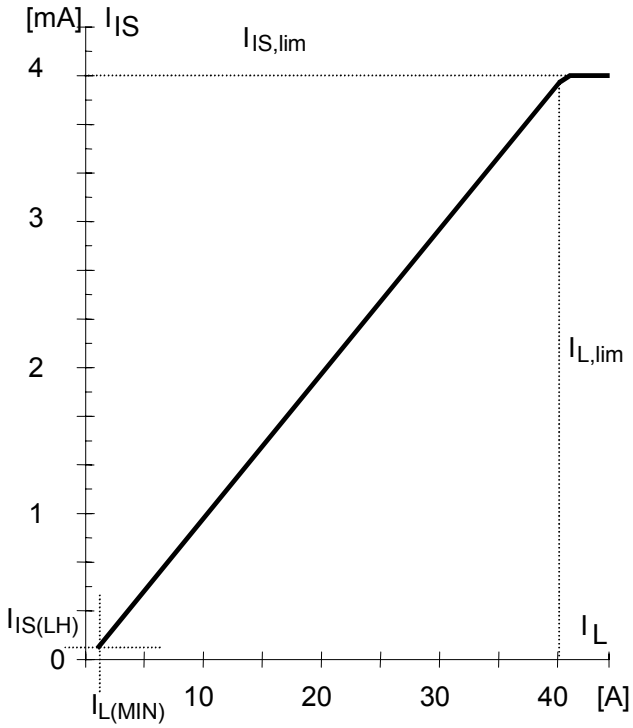
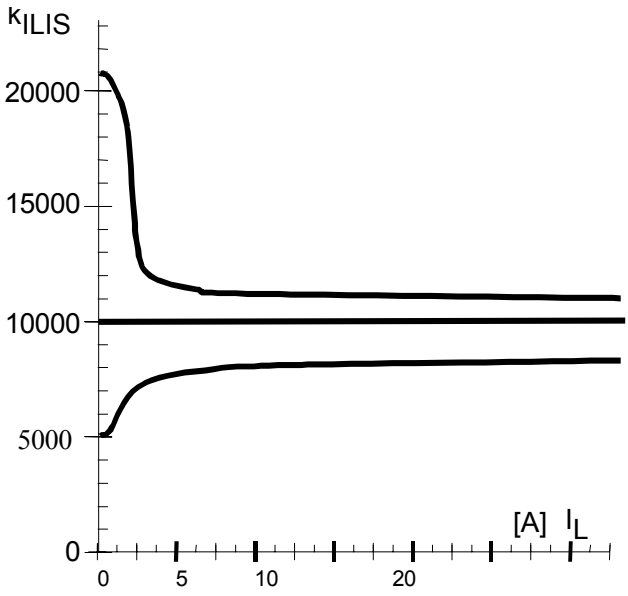
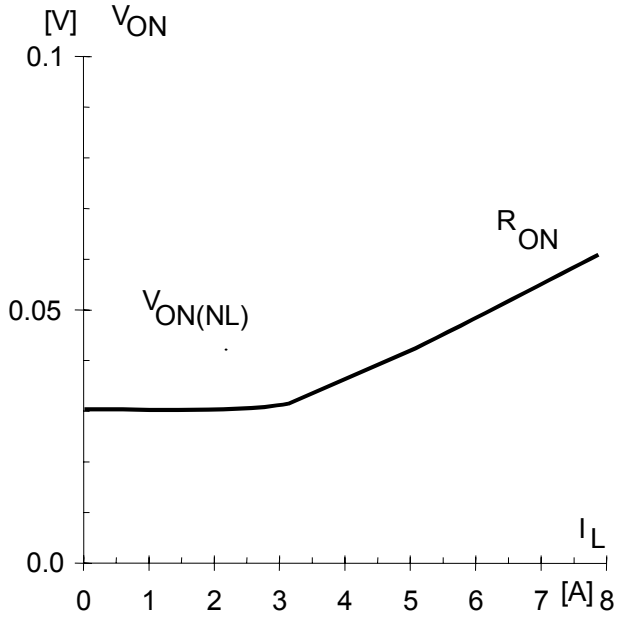


Figure 6b: Current sense ratio[22]:



[22] This range for the current sense ratio refers to all devices. The accuracy of the k_{ILIS} can be raised by means of calibration the value of k_{ILIS} for every single device.

Figure 7a: Output voltage drop versus load current:

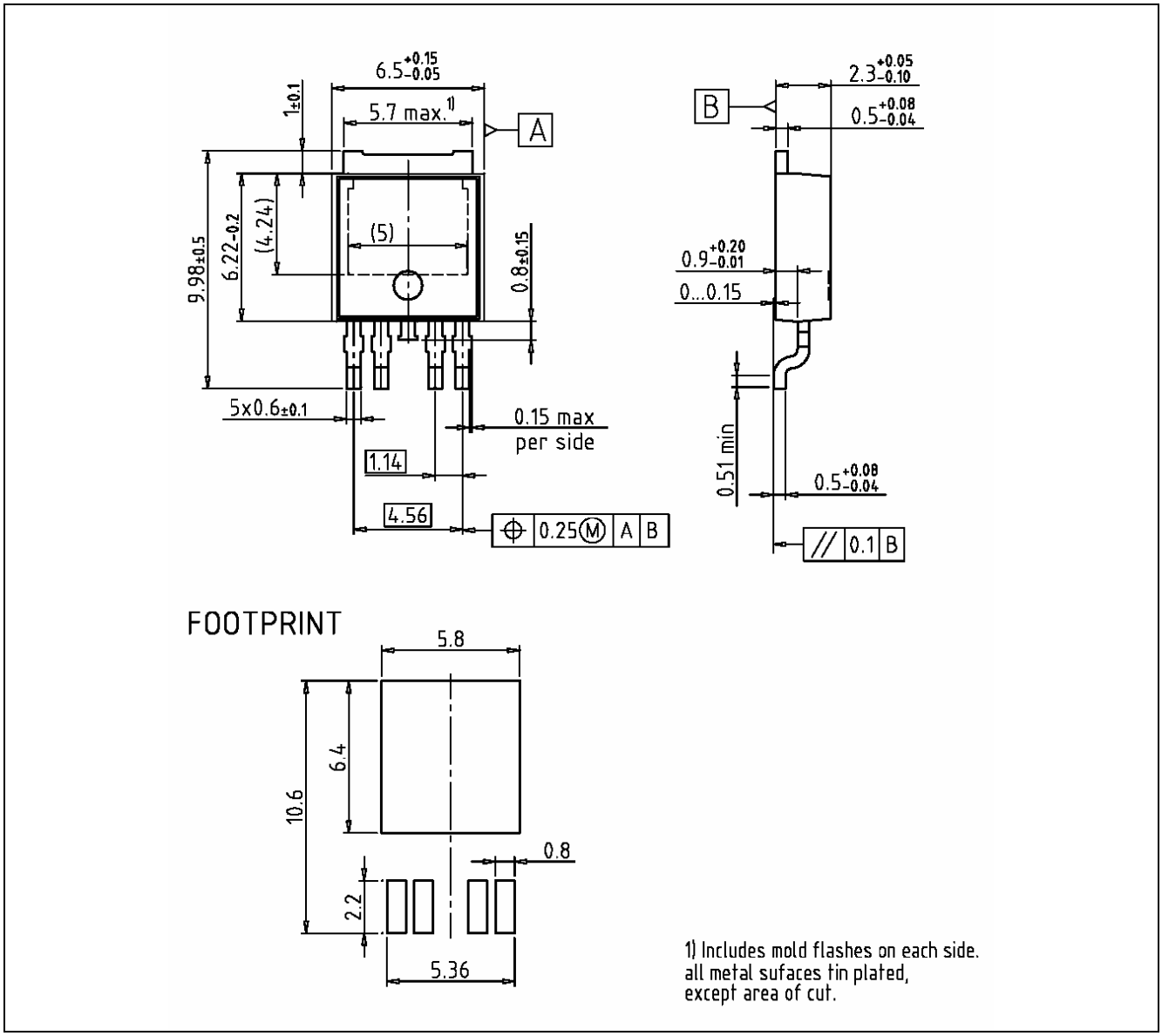


Package Outlines

All dimensions in mm

D-Pak-5 Pin: PG-TO252-5-11

Sales Code	BTS 6143 D



Green Product

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Revision History

Version	Date	Changes
Rev. 1.0	2007-02-21	RoHS-compliant version of BTS6143D Page 1, page 16: RoHS compliance statement and Green product feature added Page 1, page 16: Change to RoHS compliant package PG-TO252-5-11 Legal disclaimer updated

Edition 2007-02

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